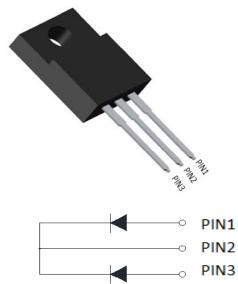


Schottky Diodes



Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

• Package: ITO-220AB

Molding compound meets UL 94 V-0 flammability

rating, RoHS-compliant

• Terminals: Tin plated leads, solderable per J-STD-

002 and JESD22-B102

• Polarity: As marked

■Maximum Ratings (Ta=25°C Unless otherwise specified)

= maximum Natings (Ta 20 0 offices office opening)					
PARAMETER	SYMBOL	UNIT	MBR2045FCTS		
Device marking code			MBR2045FCTS		
Repetitive Peak Reverse Voltage	VRRM	٧	45		
Average Rectified Output Current @60Hz sine wave, R-load, T _C =98°C	IO	Α	20		
Surge(Non-repetitive)Forward Current @60H _Z half sine-wave,1 cycle, T _a =25°C	IFSM	А	150		
Current Squared Time @1ms≤t≤8.3ms Tj=25°C,	l²t	A ² s	94		
Storage Temperature	Tstg	°C	-55 ~ + 150		
Junction Temperature	Тј	°C	-55 ~ + 150		

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

			•	
PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR2045FCTS
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=10.0A	0.65
Maximum DC reverse current at rated DC blocking voltage per diode	IRRM1	mA	VRM=VRRM T _a =25°C	0.2
	IRRM2		VRM=VRRM T _a =125°C	50

Thermal Characteristics $(T_a=25^{\circ}\mathbb{C} \text{ Unless otherwise specified})$

PARAMETER		SYMBOL	UNIT	MBR2045FCTS
Thermal Resistance	Between junction and case	R ₀ J-C	°CW	4.0

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR2045FCTS	Approximate 1.6	50	1000	5000	Tube

■Characteristics (Typical)

FIG1:lo -Tc Curve Average Forward Output Current (A) 28.0 24.0 20.0 16.0 TC measure point 12.0 • 8.0 4.0 0 0 50 100 Case Temperature (°C)

FIG2:Surge Forward Current Capability

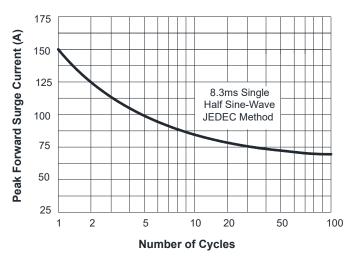


FIG3: Forward Voltage

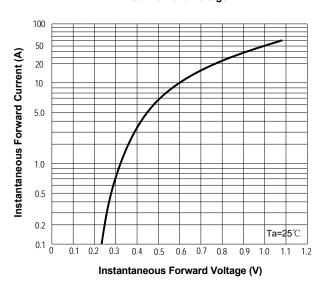
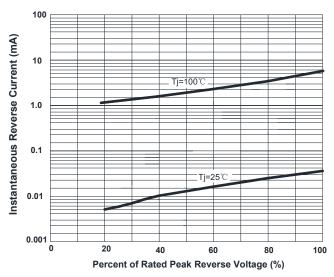
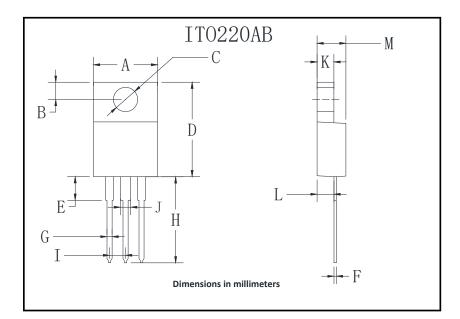


FIG.4: Typical Reverse Characteristics





■Outline Dimensions



ITO-220AB				
Dim	Min	Max		
Α	9.7	10.7		
В	2.15	3.25		
С	2.6	3.8		
D	14.4	15.9		
Е	3.1	4.5		
F	0.4	0.8		
G	0.4	0.8		
Н	12.7	14.2		
I	1.80	2.95		
J	1.4	1.8		
K	2.1	3.56		
L	2.1	3.2		
М	3.9	5.1		



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